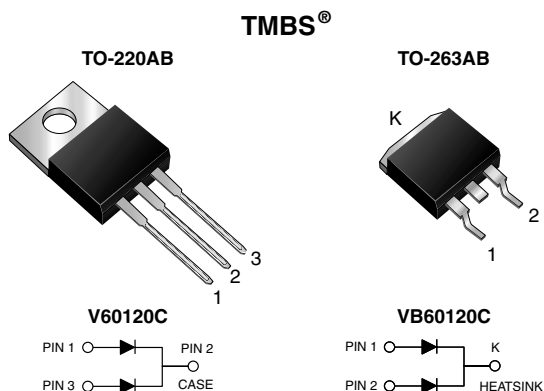




# Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.41\text{ V}$  at  $I_F = 5\text{ A}$



## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



**RoHS**  
COMPLIANT

## TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

## PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
$V_{RRM}$	120 V
$I_{FSM}$	300 A
$V_F$ at $I_F = 30\text{ A}$	0.71 V
$T_J$ max.	150 °C

## MECHANICAL DATA

**Case:** TO-220AB and TO-263AB

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

## MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V60120C	VB60120C	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	120		V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	60		A
		30		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	300		A
Non-repetitive avalanche energy at $T_J = 25\text{ °C}$ , $L = 100\text{ mH}$ per diode	$E_{AS}$	260		mJ
Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$ , 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$ per diode	$I_{RRM}$	0.5		A
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000		V/ $\mu\text{s}$
Operating junction and storage temperature range	$T_J, T_{STG}$	- 40 to + 150		°C

## V60120C, VB60120C

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**ELECTRICAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	120 (minimum)	-	V
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.48	-	V
	I <sub>F</sub> = 15 A			0.66	-	
	I <sub>F</sub> = 30 A			0.88	0.95	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.41	-	
	I <sub>F</sub> = 15 A			0.58	-	
	I <sub>F</sub> = 30 A			0.71	0.75	
Reverse current at rated V <sub>R</sub> per diode	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	14	-	μA
		T <sub>A</sub> = 125 °C		11	-	mA
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 25 °C		40	500	μA
		T <sub>A</sub> = 125 °C		15	45	mA

**Notes**(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle(2) Pulse test: Pulse width  $\leq 40\text{ ms}$ **THERMAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

PARAMETER	SYMBOL	V60120C	VB60120C	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	2.2	2.2	$^{\circ}\text{C/W}$

**ORDERING INFORMATION** (Example)

PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V60120C-E3/4W	1.89	4W	50/tube	Tube
TO-263AB	VB60120C-E3/4W	1.38	4W	50/tube	Tube
TO-263AB	VB60120C-E3/8W	1.38	8W	800/reel	Tape and reel

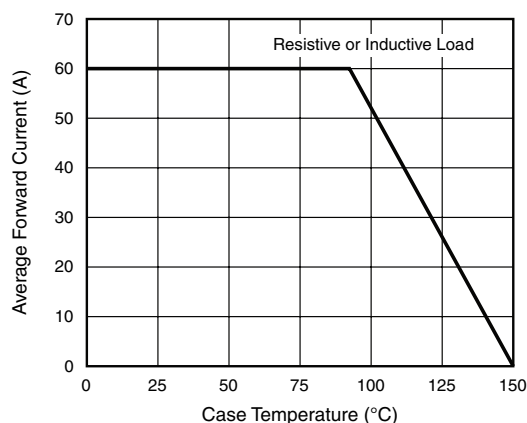
**RATINGS AND CHARACTERISTICS CURVES**( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

Fig. 1 - Forward Current Derating Curve

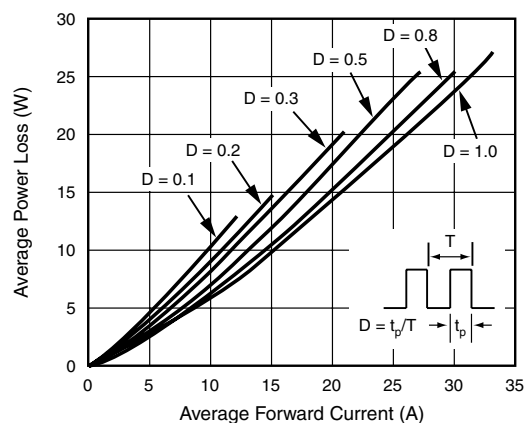


Fig. 2 - Forward Power Loss Characteristics Per Diode

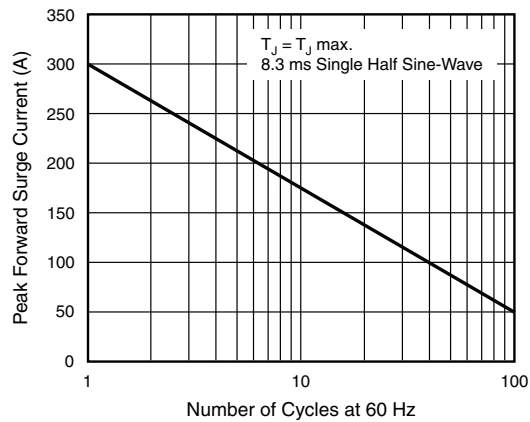


Fig. 3 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

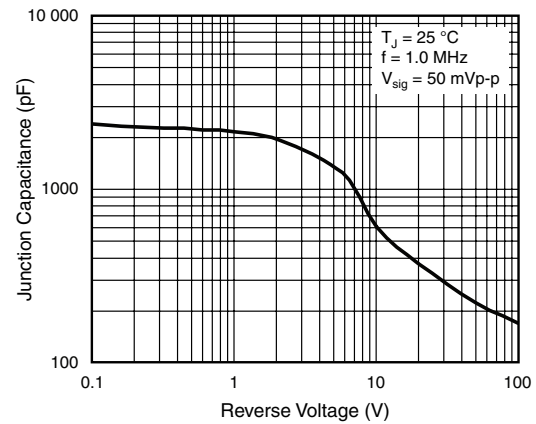


Fig. 6 - Typical Junction Capacitance Per Diode

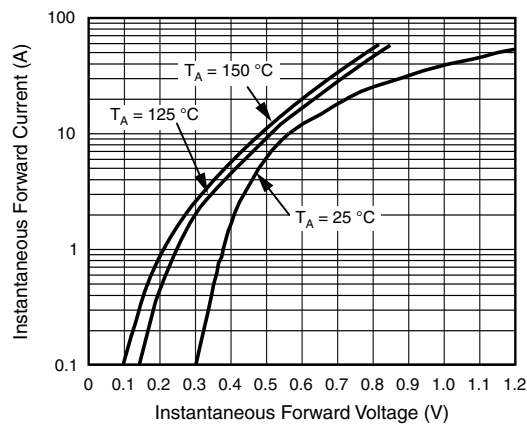


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

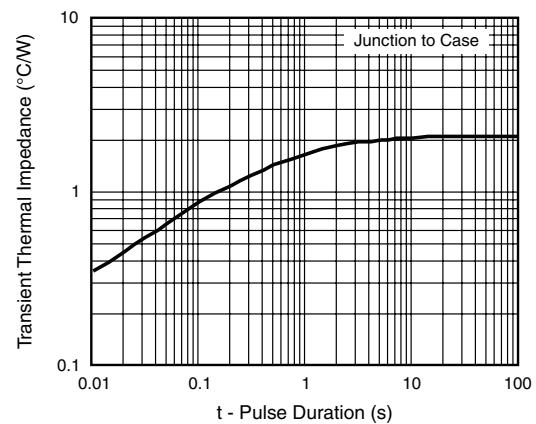


Fig. 7 - Typical Transient Thermal Impedance Per Diode

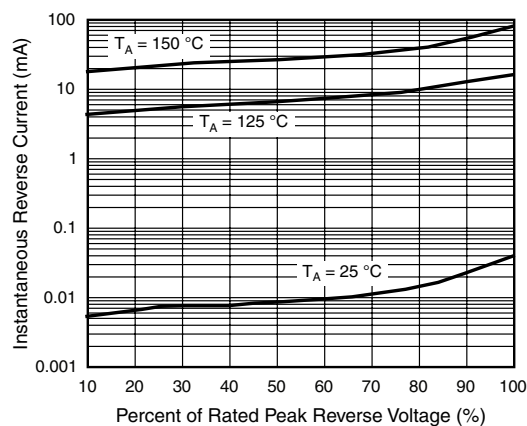
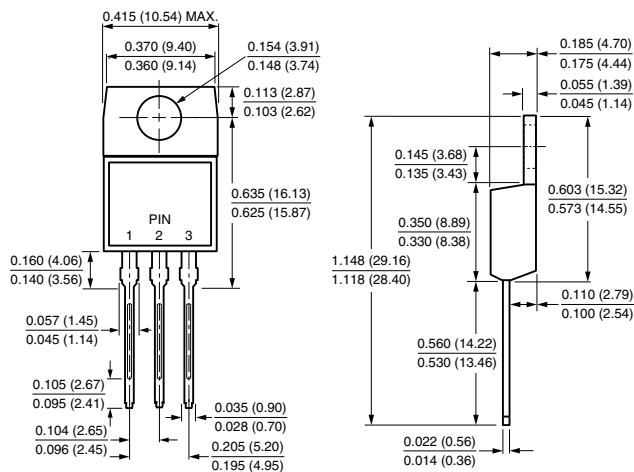
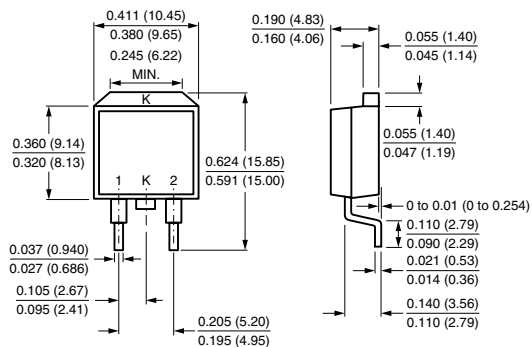
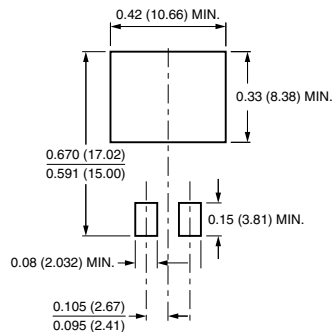


Fig. 5 - Typical Reverse Characteristics Per Diode

**V60120C, VB60120C**

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**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)**TO-220AB****TO-263AB****Mounting Pad Layout**



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